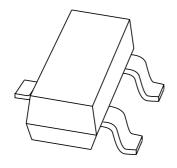
DISCRETE SEMICONDUCTORS

DATA SHEET



PLVA2600A series Low-voltage avalanche regulator double diodes

Product data sheet Supersedes data of 1999 May 10 2001 Oct 15



Low-voltage avalanche regulator double diodes

PLVA2600A series

FEATURES

- Very low dynamic impedance at low currents: approximately ¹/₂₀ of conventional series
- · Hard breakdown knee
- Low noise: approximately ¹/₁₀ of conventional series
- Total power dissipation: max. 250 mW
- Small tolerances of V_Z
- Working voltage range: nom. 5.0 to 6.8 V
- Non-repetitive peak reverse power dissipation: max. 30 W.

APPLICATIONS

- Low current, low power, low noise applications
- . CMOS RAM back-up circuits
- Voltage stabilizers
- Voltage limiters
- Smoke detector relays.

DESCRIPTION

The PLVA2600A series consists of two high performance voltage regulator diodes with common anodes, in small SOT23 plastic SMD packages.

The series consists of PLVA2650A to PLVA2668A.

MARKING

| TYPE NUMBER | MARKING CODE(1) |
|-------------|-----------------|
| PLVA2650A | *9J |
| PLVA2653A | *9K |
| PLVA2656A | *9L |
| PLVA2659A | *9M |
| PLVA2662A | *9N |
| PLVA2665A | *90 |
| PLVA2668A | *9P |

Note

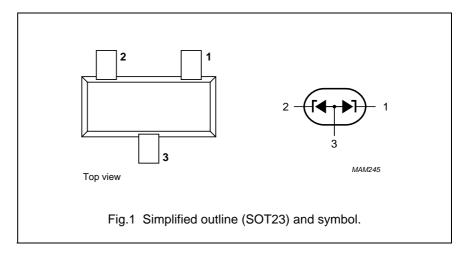
1. * = p: Made in Hong Kong.

* = t : Made in Malaysia.

* = W: Made in China.

PINNING

| PIN | DESCRIPTION | |
|-----|--------------|--|
| 1 | cathode (k1) | |
| 2 | cathode (k2) | |
| 3 | common anode | |



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---|--|------|------|------|
| I _F | continuous forward current | | - | 250 | mA |
| I_{ZRM} | repetitive peak working current | $t_p = 100 \ \mu s; \ \delta = 10\%$ | _ | 250 | mA |
| P _{ZSM} | non-repetitive peak reverse power dissipation | $t_p = 100 \ \mu s; \ T_j = 150 \ ^{\circ}C$ | - | 30 | W |
| P _{tot} | total power dissipation | single diode loaded; T _{amb} = 25 °C; note 1 | _ | 250 | mW |
| | | double diode loaded; T _{amb} = 25 °C; note 1 | _ | 180 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | = | 150 | °C |

Note

^{1.} Device mounted on an FR4 printed circuit-board.

Low-voltage avalanche regulator double diodes

PLVA2600A series

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|-------------------------|---|------|------|-------|------|
| V _F | forward voltage | I _F = 10 mA | _ | _ | 0.9 | V |
| Vz | working voltage | I _Z = 250 μA | | | | |
| | PLVA2650A | | 4.80 | 5.00 | 5.20 | V |
| | PLVA2653A | | 5.10 | 5.30 | 5.50 | V |
| | PLVA2656A | | 5.40 | 5.60 | 5.80 | V |
| | PLVA2659A | | 5.70 | 5.90 | 6.10 | V |
| | PLVA2662A | | 6.00 | 6.20 | 6.40 | V |
| | PLVA2665A | | 6.30 | 6.50 | 6.70 | V |
| | PLVA2668A | | 6.60 | 6.80 | 7.00 | V |
| | working voltage | I _Z = 10 μA | | | | |
| | PLVA2650A | | _ | 4.30 | _ | V |
| | PLVA2653A | | _ | 5.20 | _ | V |
| | PLVA2656A | | _ | 5.51 | _ | V |
| | PLVA2659A | | _ | 5.85 | _ | V |
| | PLVA2662A | | _ | 6.19 | _ | V |
| | PLVA2665A | | _ | 6.49 | _ | V |
| | PLVA2668A | | _ | 6.80 | _ | V |
| R _Z | dynamic resistance | 1 kHz superimposed; | | | | |
| | PLVA2650A | I_{ZAC} is 10% of I_{ZDC} ; $I_Z = 250 \mu A$ | _ | _ | 700 | Ω |
| | PLVA2653A | | _ | _ | 250 | Ω |
| | PLVA2656A to PLVA2668A | | _ | _ | 100 | Ω |
| Sz | temperature coefficient | I _Z = 250 μA | | | | |
| | PLVA2650A | | _ | 0.20 | _ | mV/K |
| | PLVA2653A | | _ | 1.60 | _ | mV/K |
| | PLVA2656A | | _ | 1.90 | _ | mV/K |
| | PLVA2659A | | _ | 2.40 | _ | mV/K |
| | PLVA2662A | | _ | 2.65 | _ | mV/K |
| | PLVA2665A | | _ | 2.90 | _ | mV/K |
| | PLVA2668A | | _ | 3.40 | _ | mV/K |
| I _R | reverse current | V _R = 80%; V _Z nominal | | | | |
| | PLVA2650A | | _ | _ | 20000 | nA |
| | PLVA2653A | | _ | _ | 5000 | nA |
| | PLVA2656A | | _ | _ | 1000 | nA |
| | PLVA2659A | | _ | _ | 500 | nA |
| | PLVA2662A | | _ | _ | 100 | nA |
| | PLVA2665A | | _ | _ | 50 | nA |
| | PLVA2668A | | _ | _ | 10 | nA |

Low-voltage avalanche regulator double diodes

PLVA2600A series

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|------------------------|---|------|-------|------|---------------------------|
| I _R | reverse current | V _R = 50%; V _Z nominal | | | | |
| | PLVA2650A | | _ | 34 | _ | nA |
| | PLVA2653A | | _ | 22 | _ | nA |
| | PLVA2656A | | _ | 1.1 | _ | nA |
| | PLVA2659A | | _ | 0.9 | _ | nA |
| | PLVA2662A | | _ | 0.9 | _ | nA |
| | PLVA2665A | | _ | 0.9 | _ | nA |
| | PLVA2668A | | _ | 0.8 | _ | nA |
| | reverse current | V _R = 90%; V _Z nominal | | | | |
| | PLVA2650A | | _ | 21 | _ | μΑ |
| | PLVA2653A | | _ | 3.5 | _ | μΑ |
| | PLVA2656A | | _ | 1.3 | _ | μΑ |
| | PLVA2659A | | _ | 1.0 | _ | μΑ |
| | PLVA2662A | | _ | 0.05 | _ | μΑ |
| | PLVA2665A | | _ | 0.04 | _ | μΑ |
| | PLVA2668A | | _ | 0.006 | _ | μΑ |
| ΔV_Z | line regulation | | | | | |
| | PLVA2659A to PLVA2668A | $I_{LO} = 10 \mu A; I_{Hi} = 1 mA$ | _ | _ | 0.1 | V |
| | PLVA2656A | $I_{LO} = 50 \mu A; I_{Hi} = 1 mA$ | _ | _ | 0.1 | V |
| | PLVA2650A | $I_{LO} = 100 \mu A; I_{Hi} = 1 mA$ | _ | _ | 0.4 | V |
| | PLVA2653A | $I_{LO} = 100 \mu A; I_{Hi} = 1 mA$ | _ | _ | 0.2 | V |
| V _n | noise voltage density | $f = 1 \text{ kHz}; B = 1 \text{ kHz}; I_Z = 250 \mu A$ | _ | _ | 1.0 | μV |
| | | | | | | $\frac{\mu V}{\sqrt{Hz}}$ |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th j-tp} | thermal resistance from junction to tie-point | | 360 | K/W |
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Device mounted on an FR4 printed circuit-board.

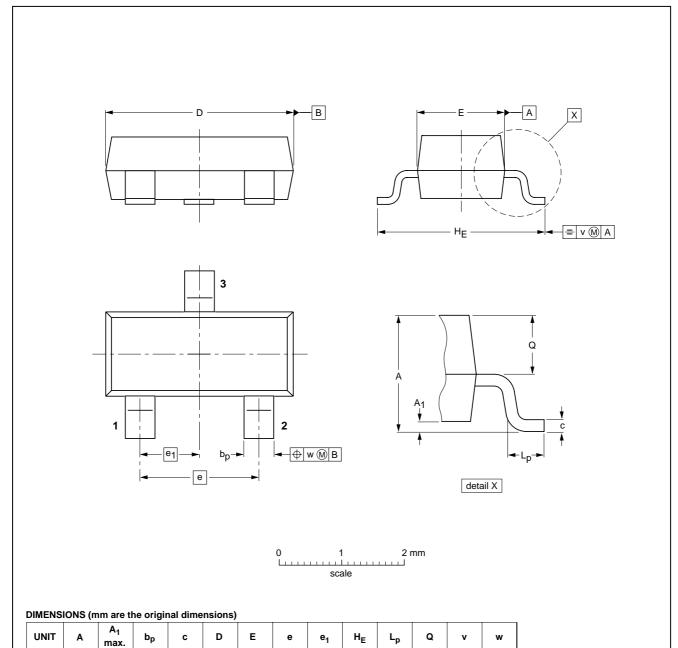
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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|------------|----------|--|----------|------------|----------------------------------|
| VERSION | IEC | JEDEC | | | 1330E DATE | |
| SOT23 | | TO-236AB | | | | -97-02-28 99-09-13 |

1.9

0.45

0.55

0.1

2001 Oct 15 6

0.48

0.38

0.15

1.1

Low-voltage avalanche regulator double diodes

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DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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- 1. Please consult the most recently issued document before initiating or completing a design.
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Printed in The Netherlands 613514/04/pp8 Date of release: 2001 Oct 15 Document order number: 9397 750 08768



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